On the Effectiveness of the Remanence Decay Side-Channel to Clone Memory-based PUFs

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Memory-based Physically Unclonable Functions (PUFs) often considered as lightweight alternative to secure non-volatile memory



Typical assumptions on memory PUF-based systems

- Reading out the secret PUF state is hard
- Re-use of existing device memory minimizes implementation costs

We show: Re-use of device memory allows reading out secret PUF state





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In This Talk

• Cloning attack against memory-based PUFs

- Exploits data remanence decay as side-channel
- Applies differential fault analysis [Biham and Shamir, CRYPTO'97] to extract secret PUF state
- Experimental and practical validation of the attack
- Countermeasures



What is a Memory-Based PUF?



Memory-Based PUFs

Major class of PUFs based on instability of volatile memory

Such as SRAM cells, flip-flops or latches

Our focus: SRAM-based PUFs



Goal: Extract unique device-specific fingerprint



SRAM-PUF



SRAM block (array of SRAM cells)



SRAM cell: pair of cross-coupled inverters

- Inverters designed identically
- Identical inverters mean state 0 and 1 is equiprobable at power-up (when bit lines are undefined)

Manufacturing variations affect properties of inverters

- Most cells are biased towards 0 or 1 at SRAM power-up
- Some cells are metastable (take 0 or 1 with equal probability)



What are Memory-Based PUFs used for?



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Typical Application: Secure Key Storage



Common assumptions

- PUF response can only be read by post processing algorithm
- Post processing and security mechanism do not leak key or PUF response

These assumptions are not sufficient!



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Why are these assumptions insufficient?



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Observation: Data Remanence Decay



Data



SRAM



SRAM stores data

Power off \Rightarrow Data slowly decays to PUF state

Power on \Rightarrow Decay stops



CHES 2013





TECHNISCHE

How to turn this into an attack?



Fault Injection Attack



Assumptions

- Adversary knows value written to the SRAM
- Adversary controls power supply of device
- Adversary can observe device behavior (e.g., a device response)



Adversary can force the security mechanism to use a wrong key that depends on a partially known memory state





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How to exploit this to extract the secret PUF state?



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Differential Fault Analysis

[Biham and Shamir, CRYPTO'97]

Two phases:

1. Data Collection Phase

Observe and record device behavior for different partially known memory states

2. Analysis Phase

Recover secret PUF state in a step-by-step fashion



Data Collection Phase



System

Security Lab

🜌 Fraunhofer

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Requirement: Difference between two consecutive memory states must be small



Does this work in practice?



Test Setup and PUF ASIC

PUF ASIC

- ASIC manufactured in TSMC 65 nm CMOS multi-project wafer run
- Includes four 8Kbyte SRAM-PUFs (amongst other PUF types)







Evaluation Result: Decay Times of SRAM Cells

Each SRAM cell has a characteristic decay time

Careful control of power-off time minimizes number of bit-changes between two consecutive experiments





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What about real systems?



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Effectiveness Against Real System

• Target system: PUF key storage and authentication scheme

- 8 KByte SRAM used as PUF
- Uses repetition code and linear encoding [Bösch et al., CHES'08]
- Generates 128 bit key from PUF response
- Key used in standard challenge/response authentication protocol

Attack complexity

- 128 bit key stored in PUF can be recovered with $\approx 2^{56}$ operations
- Key recovery can be parallelized



How to prevent the attack?



Countermeasures



Use dedicated read-only SRAM for the PUF

- Contradicts idea of using existing memory for lightweight implementations
- Not suitable for low-end embedded devices (e.g., sensors)

Wait until all memory cells have returned to PUF state

- Takes considerable amount of time
- Decay-time depends on operating conditions (e.g., temperature)

Obfuscate device behavior

- Seems to increase complexity of the algorithms and protocols
- May exceed capabilities of low-end embedded devices (e.g., sensors)



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Conclusion and Future Work

We presented

- First non-invasive cloning attack against memory-based PUFs based on the data remanence decay side channel
- Experimental and practical validation of the attack
- Performance improvement of TARDIS time-keeping mechanism for clock-less devices [Rahmati et al., USENIX'12] (see paper for details)

Current and future work

- Improving the attack
 - More precise control of decay effect (use voltage-based approach)
 - Optimize analysis phase (exploit properties of PUF post processing algorithms)





Thank you!



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